# N-Channel 30-V (D-S) MOSFET

## **Key Features:**

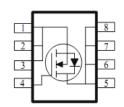
- Low r<sub>DS(on)</sub> trench technology
- · Low thermal impedance
- Fast switching speed

### **Typical Applications:**

- White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY				
VDS (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)		
30	10 @ V <sub>GS</sub> = 10V	15.3		
30	14 @ V <sub>GS</sub> = 4.5V	13.0		





ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)						
Parameter		Symbol	Limit	Units		
Drain-Source Voltage	V <sub>DS</sub>	30	V			
Gate-Source Voltage		V <sub>GS</sub>	±20	V		
Continuous Drain Current <sup>a</sup>	T <sub>A</sub> =25°C	I <sub>D</sub>	15.3	A		
Continuous Drain Current	T <sub>A</sub> =70°C		11.6			
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	50			
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	5.6	А		
Dower Dissinction <sup>a</sup>	T <sub>A</sub> =25°C	P <sub>D</sub>	3.5	W		
Power Dissipation <sup>a</sup>	T <sub>A</sub> =70°C	۰D	2			
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C		

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Maximum	Units			
Maximum Junction-to-Ambient <sup>a</sup>	t <= 10 sec	R <sub>eja</sub>	35	°C/W		
	Steady State		81	C/VV		

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

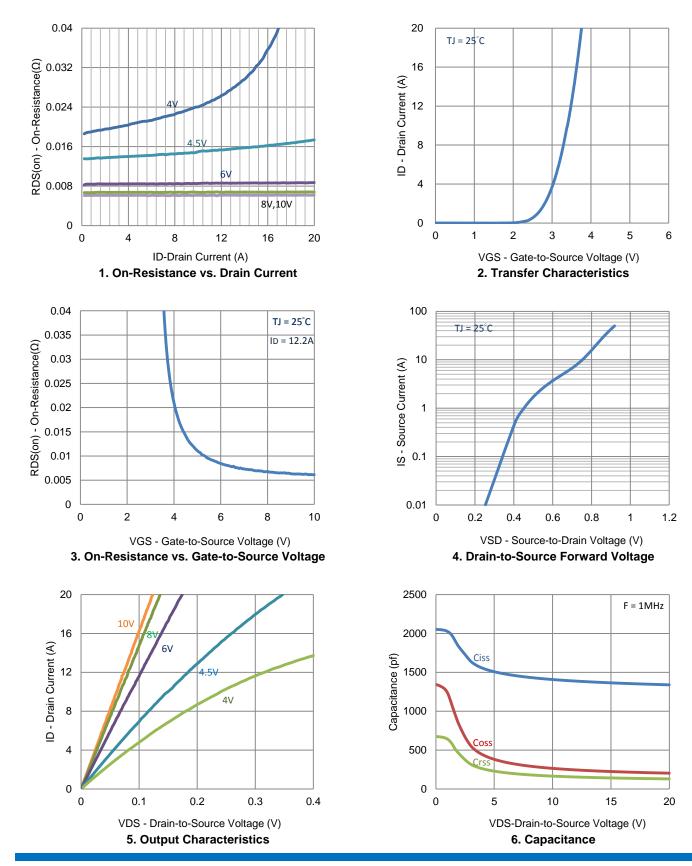
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit		
Static								
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	1			V		
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			±100	nA		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			500	uA		
On-State Drain Current	I <sub>D(on)</sub>	$V_{DS} = 5 V, V_{GS} = 10 V$	30			А		
Drain-Source On-Resistance	r	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 12.2 \text{ A}$			10			
Dialit-Source Off-Resistance	r <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 10.4 \text{ A}$			14	mΩ		
Forward Transconductance	<b>g</b> <sub>fs</sub>	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 12.2 \text{ A}$		10		S		
Diode Forward Voltage	$V_{SD}$	$I_{S} = 2.8 \text{ A}, V_{GS} = 0 \text{ V}$		0.58		V		
Dynamic								
Total Gate Charge	Qg			12				
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = 15 V, V_{GS} = 4.5 V,$ $I_{D} = 12.2 A$		5.2		nC		
Gate-Drain Charge	$Q_{gd}$	$D = 12.2 \Lambda$		5.3				
Turn-On Delay Time	t <sub>d(on)</sub>	V <sub>DS</sub> = 15 V, R <sub>L</sub> = 1.2 Ω,		6				
Rise Time	t <sub>r</sub>	$V_{DS} = 15 V, R_{L} - 1.2 \Omega,$ $I_{D} = 12.2 A,$		10		ns		
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GEN} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		28				
Fall Time	t <sub>f</sub>	$v_{\text{GEN}} = 10^{\circ} v$ , $v_{\text{GEN}} = 0.22$		11		]		
Input Capacitance	C <sub>iss</sub>			1364				
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0 V, f = 1 MHz		224		pF		
Reverse Transfer Capacitance	C <sub>rss</sub>			142		1		

# **Electrical Characteristics**

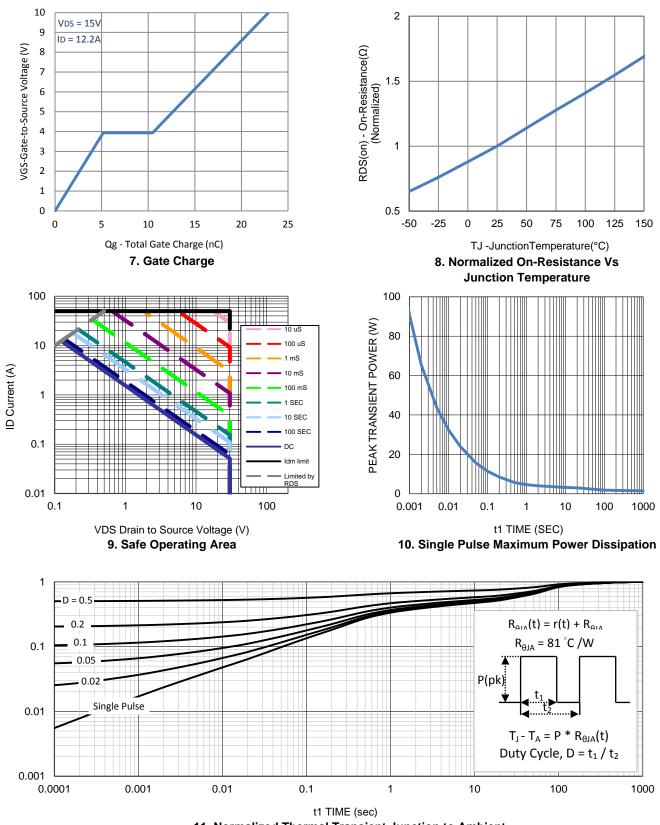
#### Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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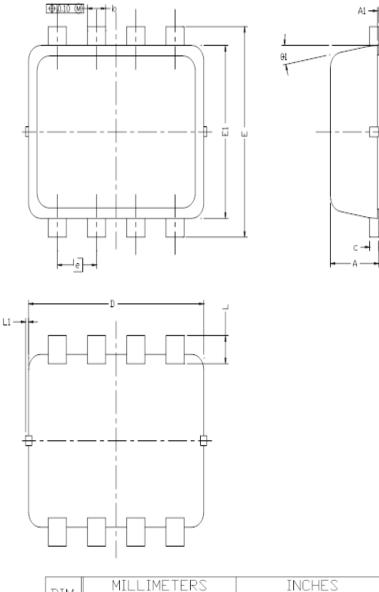
### **Typical Electrical Characteristics**



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11. Normalized Thermal Transient Junction to Ambient

# Package Information



DIM.	MILLIMETERS			INCHES			
DIM	MIN	NDM	MAX	MIN	NDM	MAX	
Α	0.700	0,80	0.900	0.0276	0.0315	0.0354	
A1	0,00		0.05	0,000		0.002	
b	0.24	0.30	0.35	0.009	0.012	0.014	
C	0.08	0.152	0.25	0.003	0.006	0.010	
D	2.90 BSC			0.114 BSC			
E	2.80 BSC			0.110 BSC			
E1	2.30 BSC			0.091 BSC		C	
e	0	0.65 BSC		0.026 BSC			
L	0,20	0.375	0.450	0.008	0.0148	0.0177	
L1	Û		0,100	0		0.004	
01	0	10	12	0	10	12	